MSKSEMI 美森科













ESD

TVS

TSS

MOV

GDT

PLED

MBR0520L-MS/MBR0530L-MS/MBR0540L-MS Product specification





Surface Mount Schottky Barrier Diodes

FEATURES

Low Forward Voltage

MARKING

MBR0520L-MS	MBR0530L-MS	MBR0540L-MS		
B2*	B3*	B4*		

PACKAGE OUTLINE

SOD-123	Circuit diagram
1	

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode

Absolute Maximum Ratings (T_a = 25℃)

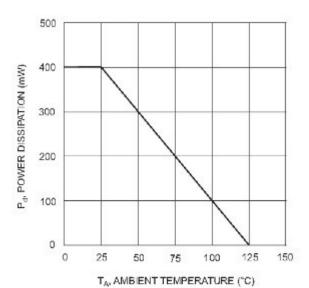
Parameter	,	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	MBR0520L-MS MBR0530L-MS MBR0540L-MS	V_{RRM}	20 30 40	V
Reverse Voltage	MBR0520L-MS MBR0530L-MS MBR0540L-MS	V _R	20 30 40	V
Average Forward Rectified Current		I _{F(AV)}	350	mA
Non-Repetitive Peak Forward Surge Current at t = 1 s		I _{FSM}	2	А
Power Dissipation		P _{tot}	400	mW
Operating and Storage Temperature Range		T _j , T _{stg}	- 65 to + 125	${\mathbb C}$

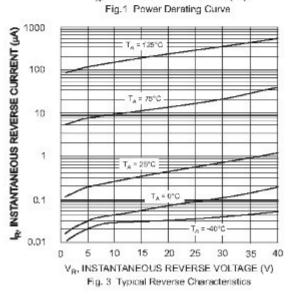
Characteristics at Ta = 25℃

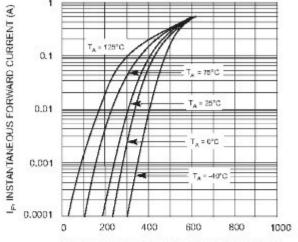
Parameter		Symbol	Min.	Тур.	Max.	Unit
Reverse Breakdown Voltage						
at $I_R = 10 \text{ uA}$	MBR0520L-MS MBR0530L-MS MBR0540L-MS	V _{(BR)R}	20 30 40		- - -	V
Reverse Leakage Current						
at VR = 10 V	MBR0520L-MS	I _R	-	-	5 5	μA
at VR = 20 V	MBR0530L-MS		-	-	5	
at VR = 30 V	MBR0540L-MS		-	-	5	
Forward Voltage at I _F = 20 mA at I _F = 200 mA		V _F	-	1 1	0.37 0.6	V
Total Capacitance at V _R = 0 V, f = 1 MHz		Ст	-	50	-	pF
Reverse Recovery Time at $I_F = I_R = 200$ mA, $I_{rr} = 0.1$	I_R , R_L = 100 Ω	t _{rr}	-	10	-	ns



Typical Characteristics







V_F, INSTANTANEOUS FORWARD VOLTAGE (mV) Fig. 2 Typical Forward Characteristics

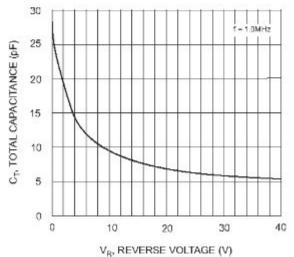
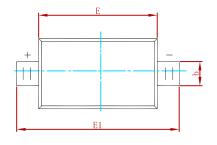
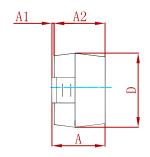


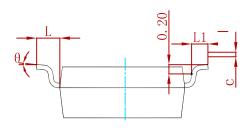
Fig. 4 Typ. Total Capacitance vs. Reverse Voltage



PACKAGE MECHANICAL DATA

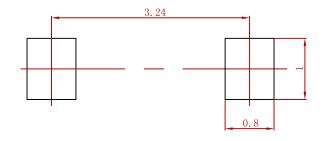






Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.450	0.650	0.018	0.026	
С	0.080	0.150	0.003	0.006	
D	1.500	1.700	0.059	0.067	
E	2.600	2.800	0.102	0.110	
E1	3.550	3.850	0.140	0.152	
Ĺ	0.500 REF		0.020	REF	
L1	0.250	0.450	0.010	0.018	
θ	0°	8°	0°	8°	

Suggested Pad Layout



Note:

- 1. Controlling dlmenslon:in mlllmeters.
- 2.General tolerance:± 0.05mm.
- 3. The pad layout Is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
MBR0520L-MS/MBR0530L-MS/MBR0540L-MS	SOD-123	3000PCS



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